NSN 5961-01-130-8552

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-130-8552 **Inclosure Material:** Glass **Overall Length:** Between 0.360 inches and 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.190 inches and 0.205 inches **Function For Which Designed:** Transient suppressor **End Application:** Ghsd 76301 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 50.00 amperes peak pulse current **Power Rating Per Characteristic:** 5.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 23426-28020 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**